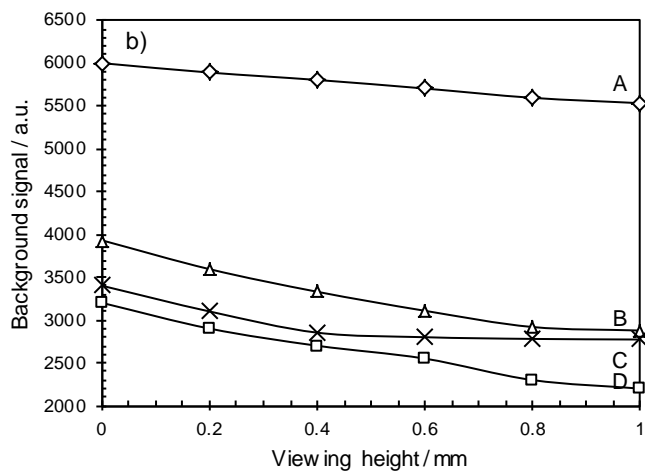
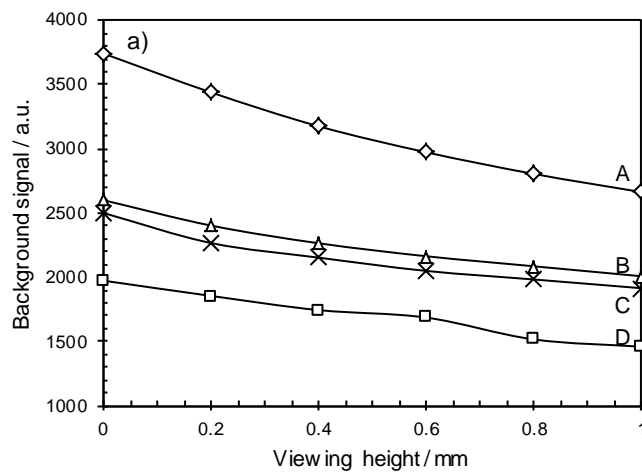


Characteristics:

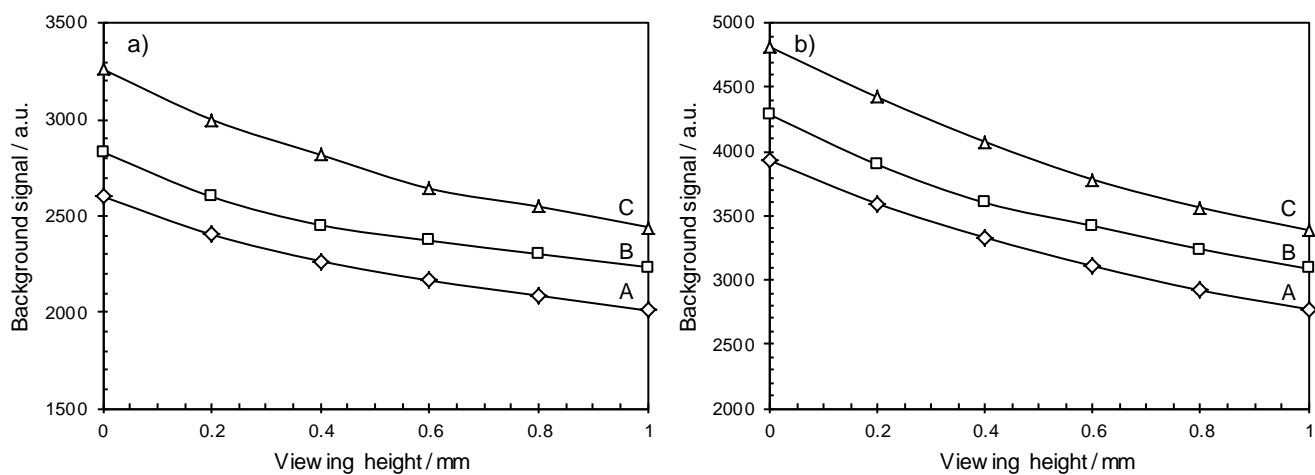
Working stroke on XYZ axis: ± 12.5 mm (total: 25 mm)

Increment: 100 μ m

Precision: 5 μ m



Electronic Supplementary Information 2. Background signal of Ar microplasma at 193.759 nm (a) and 217.581 nm (b) in HG- μ CCP-OES vs. observation height at argon flow rates (mL min⁻¹). A – 100; B – 150; C – 200; D – 300. Plasma power 10 W.



Electronic Supplementary Information 3. Background signal of Ar microplasma at 193.759 nm (a) and 217.581 nm (b) in HG- μ CCP-OES vs. observation height at different power levels (W). A – 10; B – 12; C – 15. Argon flow rate 150 mL min⁻¹.